# NSN 5961-01-141-8211

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View Online at https://aerobasegroup.com/nsn/5961-01-141-8211

# Inclosure Material:

Metal

**Overall Length:** 

1.252 inches

# Overall Height:

0.340 inches

# Overall Width:

0.700 inches

# End Application:

Transm alq99

# Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

# To-66

Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

-60.0 collector to base voltage/static/emitter open and -60.0 collector to emitter voltage/static/base open and -7.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

-4.00 amperes source cutoff current and -2.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

25.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

# **Special Features:**

Junction pattern arrangement: pnp

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

1 case and 2 pin

Specification Data:

81349-mil-s-19500/441 government specification

Shelf Life:

NI/o

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Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

